## NSN 5962-01-171-6832

Memory Microcircuit - Page 1 of 1



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Body Length:	
1.290 inches	
Body Width:	
Between 0.500 inches and 0.610 inches	
Body Height:	
0.210 inches	
Maximum Power Dissipation Rating:	
575.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and monolithic and bipolar and programmable and w/open collector	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
8 input	
Case Outline Source And Designator:	
D-3 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
140.00 nanoseconds propagation delay time, low to high level output and 140.00 nanoseconds pro	ppagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Terminal Type And Quantity:	
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Filg:	
A458a0	